NSN 5962-01-460-5926

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Maximum Power Dissipation Rating:
4.9 watts
Operating Tempurature Range:
-55.0/+175.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Valve-select e/i fscm 70339
Features Provided:
Burn in and electrostatic sensitive and hermetically sealed and monolithic and w/clock and radiation hardened and tested to mil-std-883
Inclosure Configuration:
Leaded chip carrier
Product Name:
Microckt, master image, ipu
Voltage Rating And Type Per Characteristic:
0.0 volts input and 7.0 volts input
Special Features:
Tld specifies requirements for high density, monolithic silicon, nmos, "instruction processor unit" ipu devicepkg in either decal pgk 6963820
or a decal conversion pkg 6103381 and provide for 3 sorts of speed performance
Nuclear Hardness Critical Feature:
Hardened
Precious Material And Location:
Cover gold
Precious Material:
Gold
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
240 case
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A458a0